## NSN 5962-01-376-2185

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-376-2185
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Electrostatic sensitive and programmed
Inclosure Configuration:
Leaded chip carrier
Input Circuit Pattern:
16 input
Case Outline Source And Designator:
C-2 mil-m-38510
Current Rating Per Characteristic:
100.00 milliamperes reverse current, dc
Product Name:
Logic array, programmable-sdp processor u25
Voltage Rating And Type Per Characteristic:
-0.5 volts total supply and 7.0 volts total supply
Memory Device Type:
Pal
Hybrid Technology Type:
Monolithic
Test Data Document:
81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). And 96906-mil-std-883
standard (includes industry or association standards, individual manufactureer standards, etc.). And 96906-mil-std-1686 standard (includes
industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
20 printed circuit
Specification Data:
67268-80136072a government standard and 73030-800048-2 manufacturers source control
Departure From Cited Designator:
Altered by programming and marking
Shelf Life:
N/a
Unit Of Measure:
<del></del>
Demilitarization:

**Fiig:** A458a0

Yes - demil/mli